## **Declaration, Power of Attorney and Petition**

Page 1 of 3

WE (I) the undersigned inventor(s), hereby declare(s) that:

My residence, post office address and citizenship are as stated below next to my name,

We (I) believe that we are (I am) the original, first and joint (sole) inventor(s) of the subject matter which is

claimed and for which a patent		n entitled	subject matter which is
SEMICONDUCTOR DE	VICE AND MANUF	ACTURING METHOD OF	THE SAME
the specification of which			
X is attached he	ereto.		
was filed on	was filed on as		
Application S	Serial No.		
and amended	on	•	
was filed as l	PCT international applica	ation	
Number			
on		,	
and was ame	nded under PCT Article	19	
on	(if	applicable).	
including the claims, as amende	ed by any amendment ref	inderstand the contents of the aboverred to above.  In known to be material to the paten	
as defined in Section 1.56 of Ti			•
application(s) for patent or inveat least one country other than any foreign application for pa	entor's certificate, or § 36 the United States, listed tent or inventor's certifi	der 35 U.S.C. § 119(a)-(d) or § 65(a) of any PCT International app below and have also identified bel cate, or PCT International applicated. Prior Foreign Application(s)	lication which designated ow, by checking the box,
Application No.	Country	Day/Month/Year	Priority Claimed
P2002-278088	Japan	24/September/2002	⊠ Yes □ No
			☐ Yes ☐ No
			☐ Yes ☐ No
			☐ Yes ☐ No

We (I) hereby claim the benefit under Titl application(s) listed below.	e 35, United States	Code, § 119(e) of any United States provisional
(Application Number)		(Filing Date)
(Application Number)		(Filing Date)
any PCT International application designating each of the claims of this application is not disthe manner provided by the first paragraph of 3	the United States, I sclosed in the prior 5 U.S.C. § 112, I ac R § 1.56 which bec	United States application(s), or under § 365(c) of listed below and, insofar as the subject matter of United States or PCT International application in knowledge the duty to disclose information which ame available between the filing date of the prior application.
Application Serial No.	Filing Date	Status (pending, patented, abandoned)
And we (I) hereby appoint the following	registered practition	er(s):
	22850	
		on, to prosecute this application and to transact all eby request that all correspondence regarding this
	22850	
on information and belief are believed to be to that willful false statements and the like so mad	rue; and further that te are punishable by	h knowledge are true and that all statements made these statements were made with the knowledge fine or imprisonment, or both, under Section 1001 se statements may jeopardize the validity of the
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Date		

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NAME OF THIRD JOINT INVENTOR	Residence:
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Signature of Inventor	
	Mailing Address:
Date	
NAME OF FOURTH JOINT INVENTOR	Residence:
NAME OF TOOKINGON'S INVENTOR	
	CV.
Signature of Inventor	Citizen of:
	Mailing Address:
Date	
NAME OF FROM JONETH WANTON	Residence:
NAME OF FIFTH JOINT INVENTOR	
Signature of Inventor	Citizen of:
organicate of inventor	Mailing Address:
Date	